AUTOMOTIVE

ROHS

HALOGEN

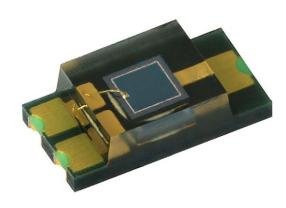
FREE GREEN

(5-2008)



Vishay Semiconductors

Silicon PIN Photodiode



DESCRIPTION

VEMD6010X01 is a high speed and high sensitive PIN photodiode. It is a small surface mount device (SMD) including the chip with a 0.85 mm² sensitive area detecting visible and near infrared radiation.

FEATURES

- Package type: surface-mount
- Package form: 1206
- Dimensions (L x W x H in mm): 4 x 2 x 1.05
- Radiant sensitive area (in mm²): 0.85
- · High photo sensitivity
- High sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity: $\varphi = \pm 60^{\circ}$
- Floor life: 72 h, MSL 4, according to J-STD-020
- · Lead (Pb)-free reflow soldering
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



· High speed photo detector

PRODUCT SUMMARY				
COMPONENT	I _{ra} (μΑ)	φ (°)	λ _{0.1} (nm)	
VEMD6010X01	9.5	± 60	430 to 1100	

Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VEMD6010X01	Tape and reel	MOQ: 3000 pcs, 3000 pcs/reel	1206		

Note

· MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		V_{R}	32	V	
Power dissipation	T _{amb} ≤ 25 °C	P _V	215	mW	
Junction temperature		Tj	110	°C	
Ambient temperature range		T _{amb}	-40 to +110	°C	
Storage temperature range		T _{stg}	-40 to +110	°C	
Soldering temperature	According to reflow solder profile Fig. 8	T _{sd}	260	°C	
Thermal resistance junction to ambient	According to J-STD-051	R _{thJA}	270	K/W	

BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 50 mA	V _F	-	1	-	V
Breakdown voltage	I _R = 100 μA, E = 0	V _(BR)	32	-	-	V
Reverse dark current	V _R = 10 V, E = 0	I _{ro}	=	1	3	nA
Diode capacitance	$V_R = 0 \text{ V, } f = 1 \text{ MHz, } E = 0$	C_D	=	12	-	pF
	$V_R = 5 \text{ V, f} = 1 \text{ MHz, E} = 0$	C _D	=	3.6	-	pF
Open circuit voltage	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm}$	Vo	=	356	-	mV
Temperature coefficient of Vo	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK _{Vo}	-	-3.1	-	mV/K
Short circuit current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	I _k	=	9	-	μA
Temperature coefficient of I _k	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm}$	TK _{lk}	=	0.1	-	%/K
Reverse light current	$E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$, $V_R = 5 \text{ V}$	I _{ra}	6.7	9.5	12.4	μA
Angle of half sensitivity		φ	-	± 60	-	0
Wavelength of peak sensitivity		λ_{p}	=	900	-	nm
Range of spectral bandwidth		λ _{0.1}	-	430 to 1100	-	nm
Rise time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t _r	=	100	-	ns
Fall time	$V_R = 10 \text{ V}, R_L = 1 \text{ k}\Omega, \lambda = 820 \text{ nm}$	t _f	-	100	-	ns

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

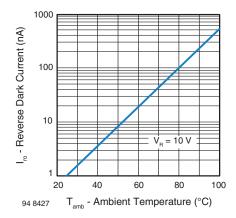


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

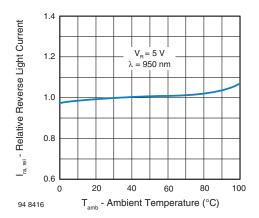


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

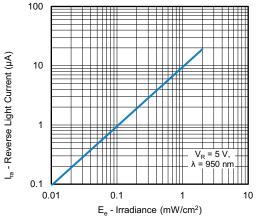


Fig. 3 - Reverse Light Current vs. Irradiance

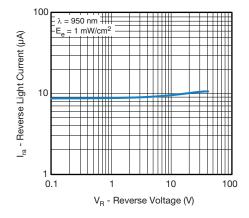


Fig. 4 - Reverse Light Current vs. Reverse Voltage

C_D - Diode Capacitance (pF)

1.0

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REFLOW SOLDER PROFILE

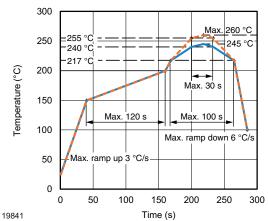


Fig. 8 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020

12 E = 0= 1 MHz 10 8 6 2 O 10 0.1 100 V_R - Reverse Voltage (V) 18438

Fig. 5 - Diode Capacitance vs. Reverse Voltage

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

$S(\lambda)_{rel}$ - Relative Spectral Sensitivity 0.8 0.6 0.4 0.2 400 500 600 700 800 900 1000 1100

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 72 h

Conditions: T_{amb} < 30 °C, RH < 60 %

Moisture sensitivity level 4, acc. to J-STD-020.

Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

λ - Wavelength (nm)

DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

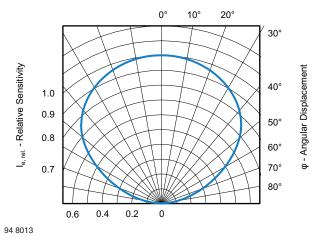
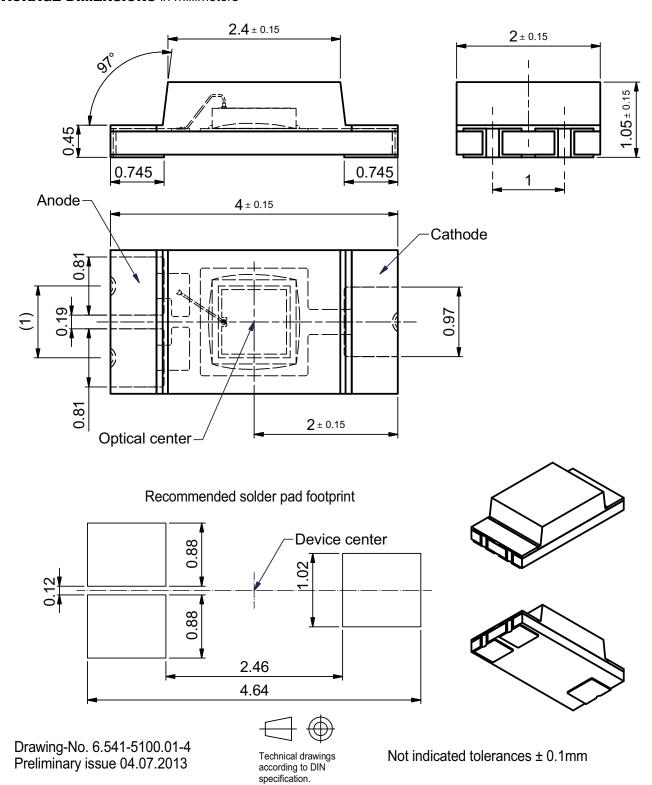
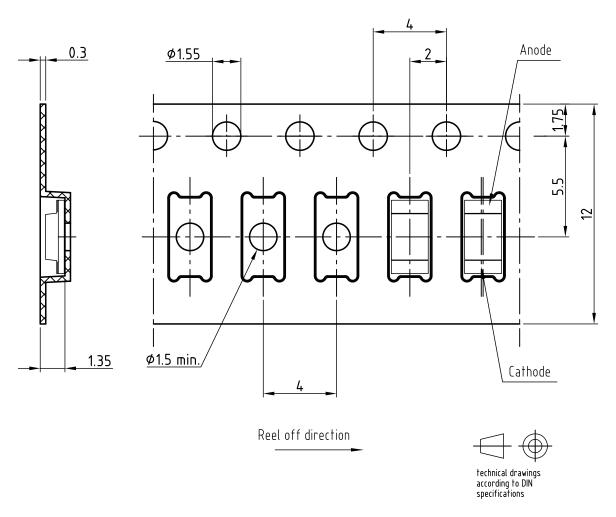


Fig. 7 - Relative Sensitivity vs. Angular Displacement

PACKAGE DIMENSIONS in millimeters



BLISTER TAPE DIMENSIONS in millimeters



Not indicated tolerances ±0.1

Drawing refers to following Types: TEMD6010FX01

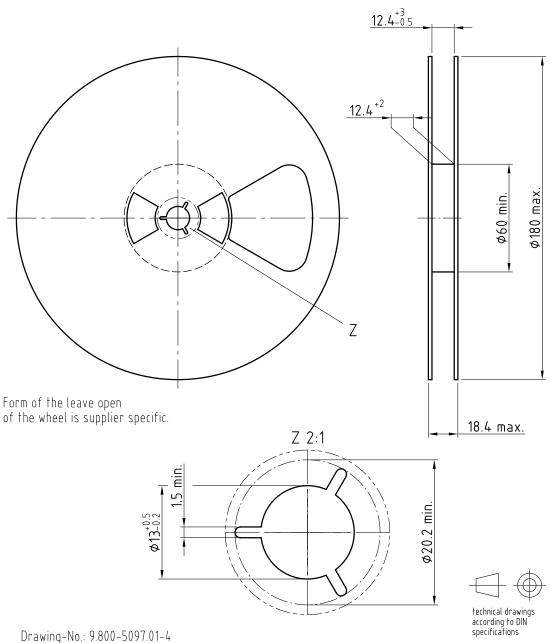
VEMD6x10X01 VEMD6x15X01

Drawing-No.: 9.700-5329.02-4

Prel Issue: 16.07.2013

All dimensions in mm

REEL DIMENSIONS in millimeters



Issue: 1; 05.05.08

20874



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